



# Microchannel Water-Cooled Single Laser Diode Bar LDBxxxCxWI

Data Sheet



## Description

The LDBxxxCxWI 808nm, 9xxnm and 1064nm microchannel water-cooled, high power laser diode bar offers up to 100 Watts CW. With its scalable power, the diode laser packaged bar can be used in a pumping, industrial and medical applications that require high-peak power. The compact package can be configured for enhanced brightness through stacking, scaled linearly or vertically for optimized light and material integration.

## Features

- 808nm/915nm/940nm/980nm/1064nm Microchannel Water-Cooled Packaged Diode Laser Bar
- High output power: Up to 100W CW
- High brightness
- Modular and compact design for ease of integration
- Packaged 10mm laser diode bar

## Applications

- Pumping
- Industrial
- Medical
- Printing
- Scientific research

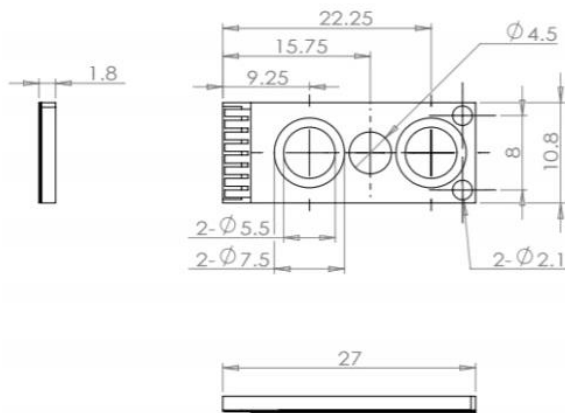
Specifications ( $T_C = 25^\circ\text{C}$ )

Part Number	LDB808C40WI	LDB808C60WI	LDB808C100WI
<b>Optical Characteristics</b>			
Center wavelength ( $\lambda_c$ )	808 nm	808 nm	808 nm
Operation mode	CW	CW	CW
Output power ( $P_o$ )	40 W	60 W	100 W
Spectral width ( $\Delta\lambda$ )	<5 nm	<5 nm	<5 nm
Wavelength Temp coefficient	0.28 nm/ $^\circ\text{C}$	0.28 nm/ $^\circ\text{C}$	0.28 nm/ $^\circ\text{C}$
Fast axis divergence ( $\theta_{\perp}$ )	<39 deg	<39 deg	<39 deg
Slow axis divergence ( $\theta_{\parallel}$ )	<10 deg	<10 deg	<10 deg
<b>Electrical Characteristics</b>			
Threshold current ( $I_{th}$ )	<7 A	<15 A	<25 A
Operating current ( $I_{op}$ )	<40 A	<70 A	<110 A
Operating voltage ( $V_{op}$ )	<2.0 V	<2.0 V	<2.0 V
<b>Thermal Characteristics</b>			
Max. Inlet pressure	65 psi	65 psi	65 psi
Cooling rate	$\geq 0.3$ l/min	$\geq 0.3$ l/min	$\geq 0.3$ l/min
Cooling medium particle size	$\leq 15$ $\mu\text{m}$	$\leq 15$ $\mu\text{m}$	$\leq 15$ $\mu\text{m}$
Cooling medium conductivity	5 to 10 $\mu\text{s/cm}$	5 to 10 $\mu\text{s/cm}$	5 to 10 $\mu\text{s/cm}$
Operating temperature ( $T_{op}$ )	15 to 35 $^\circ\text{C}$	15 to 35 $^\circ\text{C}$	15 to 35 $^\circ\text{C}$
Storage temperature ( $T_{stg}$ )	-10 to +60 $^\circ\text{C}$	-10 to +60 $^\circ\text{C}$	-10 to +60 $^\circ\text{C}$

Part Number	LDB915C60WI	LDB940C60WI	LDB980C60WI
<b>Optical Characteristics</b>			
Center wavelength ( $\lambda_c$ )	915 nm	940 nm	980 nm
Operation mode	CW	CW	CW
Output power ( $P_o$ )	60 W	60 W	60 W
Spectral width ( $\Delta\lambda$ )	<5 nm	<5 nm	<5 nm
Wavelength Temp coefficient	0.28 nm/ $^\circ\text{C}$	0.28 nm/ $^\circ\text{C}$	0.28 nm/ $^\circ\text{C}$
Fast axis divergence ( $\theta_{\perp}$ )	<39 deg	<39 deg	<39 deg
Slow axis divergence ( $\theta_{\parallel}$ )	<10 deg	<10 deg	<10 deg
<b>Electrical Characteristics</b>			
Threshold current ( $I_{th}$ )	<15 A	<15 A	<15 A
Operating current ( $I_{op}$ )	<70 A	<70 A	<70 A
Operating voltage ( $V_{op}$ )	<2.0 V	<2.0 V	<2.0 V
<b>Thermal Characteristics</b>			
Max. Inlet pressure	65 psi	65 psi	65 psi
Cooling rate	$\geq 0.3$ l/min	$\geq 0.3$ l/min	$\geq 0.3$ l/min
Cooling medium particle size	$\leq 15$ $\mu\text{m}$	$\leq 15$ $\mu\text{m}$	$\leq 15$ $\mu\text{m}$
Cooling medium conductivity	5 to 10 $\mu\text{s/cm}$	5 to 10 $\mu\text{s/cm}$	5 to 10 $\mu\text{s/cm}$
Operating temperature ( $T_{op}$ )	15 to 35 $^\circ\text{C}$	15 to 35 $^\circ\text{C}$	15 to 35 $^\circ\text{C}$
Storage temperature ( $T_{stg}$ )	-10 to +60 $^\circ\text{C}$	-10 to +60 $^\circ\text{C}$	-10 to +60 $^\circ\text{C}$

Part Number	LDB1064C40WI
<b>Optical Characteristics</b>	
Center wavelength ( $\lambda_c$ )	1064 nm
Operation mode	CW
Output power ( $P_o$ )	40 W
Spectral width ( $\Delta\lambda$ )	<5 nm
Wavelength Temp coefficient	0.28 nm/°C
Fast axis divergence ( $\theta_{\perp}$ )	<39 deg
Slow axis divergence ( $\theta_{\parallel}$ )	<10 deg
<b>Electrical Characteristics</b>	
Threshold current ( $I_{th}$ )	<7 A
Operating current ( $I_{op}$ )	<50 A
Operating voltage ( $V_{op}$ )	<2.0 V
<b>Thermal Characteristics</b>	
Max. Inlet pressure	65 psi
Cooling rate	$\geq 0.3$ l/min
Cooling medium particle size	$\leq 15$ $\mu$ m
Cooling medium conductivity	5 to 10 $\mu$ s/cm
Operating temperature ( $T_{op}$ )	15 to 35 °C
Storage temperature ( $T_{stg}$ )	-10 to +60 °C

### Mechanical Outline (unit: mm)



### Notes

1. Specifications are subject to change without notice. Ensure that you have the latest specification by contacting us prior to purchase or use of the product.
2. Please make sure that the laser diode is operated under the temperature between 15 °C and 35 °C, as high temperature will increase threshold current, decrease exchange rate and accelerate the aging.
3. Please take measures to avoid condensation, which will cause aging of laser diode.
4. Take precautions to avoid electrostatic discharge and/or momentary power spikes. A change in the characteristics of the laser or premature failure may result.
5. Observing visible or invisible laser beams with human eye directly, or indirectly, can cause permanent damage. Do not look directly into the laser output port.